

RKZ6.2Z4MFAKT

Silicon Planar Zener Diode for Surge Absorption

REJ03G1349-0100 Rev.1.00 Feb 21, 2006

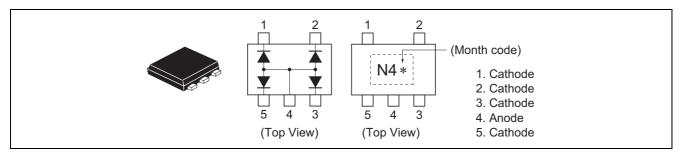
Features

- RKZ6.2Z4MFA has four devices in a monolithic, and can absorb surge.
- Low capacitance (C = 4.0 pF Typ) and can protect ESD of signal line.
- VSON-5 Package is suitable for high density surface mounting.

Ordering Information

Type No.	Laser Mark	Package Name	Package Code	
RKZ6.2Z4MFAKT	N4	VSON-5	PUSN0005KB-A	

Pin Arrangement



Month Code

	Assemble			Assemble	
Month of Manufacture	JAPAN	MALAYSIA	Month of Manufacture	JAPAN	MALAYSIA
January	А	1	July	G	7
February	В	2	August	Н	8
March	С	3	September	J	9
April	D	4	October	К	W
Мау	E	5	November	L	Х
June	F	6	December	М	Y



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

ltem	Symbol	Value	Unit
Power dissipation	Pd *	150	mW
Junction temperature	Тј	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: Four device total, See Fig.2.

Electrical Characteristics *1

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Zener voltage	Vz	5.90	—	6.50	V	$I_Z = 5 \text{ mA}, 40 \text{ ms pulse}$
Reverse current	I _R	—	—	3	μA	V _R = 5.5 V
Capacitance	С	—	4.0	4.5	pF	$V_R = 0 V$, f = 1 MHz
Dynamic resistance	r _d	_	—	60	Ω	$I_Z = 5 \text{ mA}$
ESD-Capability *2, *3	—	8	—	_	kV	C = 150 pF, R = 330 Ω , Both forward and
						reverse direction 10 pulse

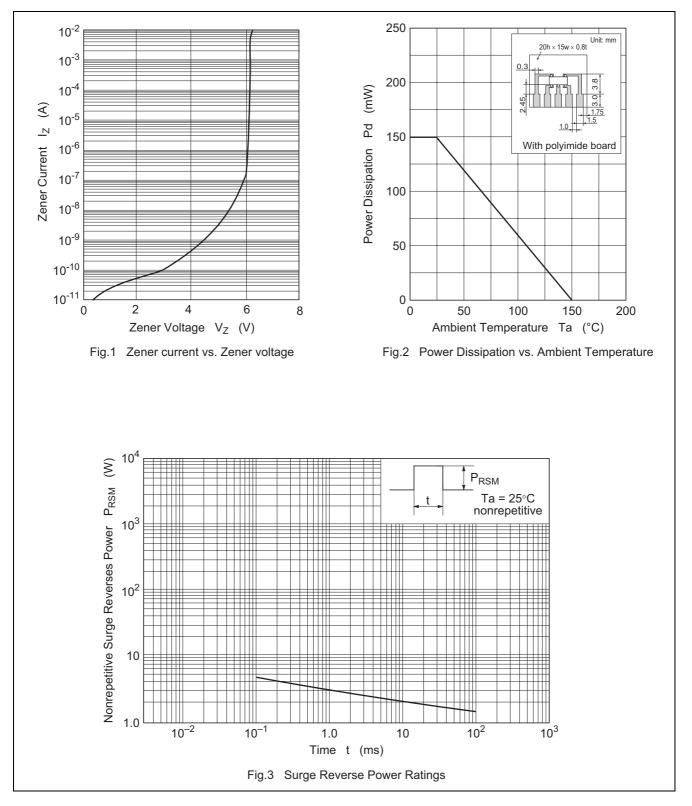
Notes: 1. Per one device.

2. Failure criterion ; I_R > 3 μA at V_R = 5.5 V.

3. Between cathode and anode.

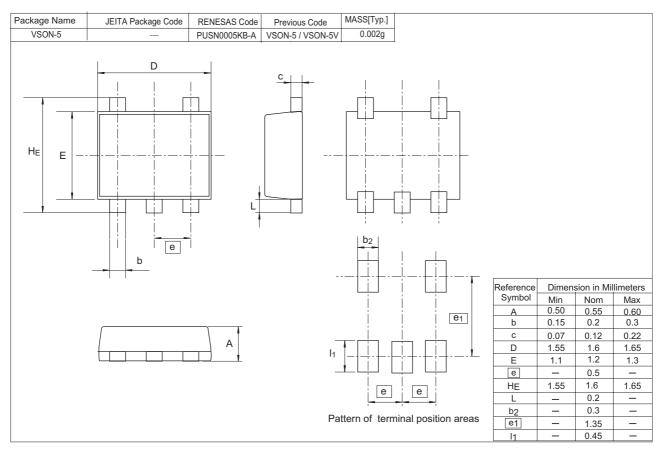


Main Characteristics



Rev.1.00 Feb 21, 2006 page 3 of 4

Package Dimensions





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